74LV541

Octal buffer/line driver; 3-state Rev. 03 — 14 April 2009

Product data sheet

1. **General description**

The 74LV541 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC541 and 74HCT541.

The 74LV541 has octal non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs OE1 and OE2. A HIGH on OEn causes the outputs to assume a high-impedance OFF-state.

2. **Features**

- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical output ground bounce < 0.8 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Typical HIGH-level output voltage (V_{OH}) undershoot: > 2 V at V_{CC} = 3.3 V and $T_{amb} = 25 \, ^{\circ}C$
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Non-inverting outputs
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Ordering information

Table 1. **Ordering information**

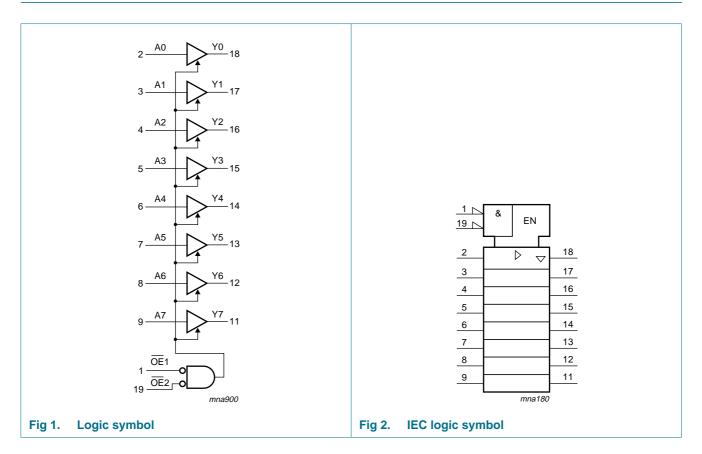
Type number	Package										
	Temperature range	Name	Description	Version							
74LV541N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1							
74LV541D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1							
74LV541DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1							
74LV541PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1							



Octal buffer/line driver; 3-state

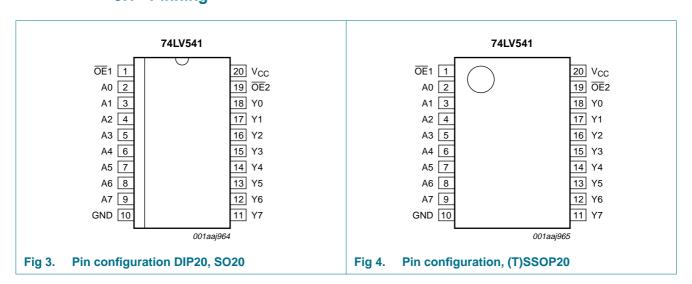
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4. Functional diagram



5. Pinning information

5.1 Pinning



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Product data sheet

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5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1	1	output enable input (active LOW)
A0 to A7	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
Y0 to Y7	18, 17, 16, 15, 14, 13, 12, 11	data output
OE2	19	output enable input (active LOW)
V_{CC}	20	supply voltage

6. Functional description

Table 3. Functional table[1]

Control		Input	Output
OE1	OE2	An	Yn
L	L	L	L
L	L	Н	Н
X	Н	X	Z
Н	X	X	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	50	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	35	mA
I _{CC}	supply current		-	70	mA
I_{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]		
		DIP20	-	750	mW
		SO20, SSOP20, TSSOP20	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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^[2] For DIP20 packages: above 70 °C the value of P_{tot} derates linearly with 12 mW/K. For SO20 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For (T)SSOP20 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

Octal buffer/line driver; 3-state

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage[1]		1.0	3.3	3.6	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage	0	-	V_{CC}	V	
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	-	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	-	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	100	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to V_{CC} = 3.6 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 1.2 \text{ V}$	-	-	0.3	-	0.3	V
		$V_{CC} = 2.0 \text{ V}$	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	8.0	-	8.0	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		I_O = $-100 \mu\text{A}; V_{CC}$ = $1.2 V$	-	1.2	-	-	-	V
		$I_O = -100 \ \mu A; \ V_{CC} = 2.0 \ V$	1.8	2.0	-	1.8	-	V
		I_O = $-100~\mu A$; V_{CC} = $2.7~V$	2.5	2.7	-	2.5	-	V
		I_{O} = -100 μ A; V_{CC} = 3.0 V	2.8	3.0	-	2.8	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.82	-	2.2	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		I_O = 100 μ A; V_{CC} = 1.2 V	-	0	-	-	-	V
		I_O = 100 μ A; V_{CC} = 2.0 V	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 2.7 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.2	-	0.2	V
		I_{O} = 8 mA; V_{CC} = 3.0 V	-	0.2	0.40	-	0.50	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	5	-	10	μΑ

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Octal buffer/line driver; 3-state

 Table 6.
 Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 3.6 \text{ V}$	-	-	20	-	160	μΑ
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
C _I	input capacitance		-	3.5	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 7.

Symbol	Parameter	Conditions		-40	°C to +85	S °C	–40 °C t	Unit	
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	An to Yn; see Figure 5	[2]		•				
		V _{CC} = 1.2 V		-	60	-	-	-	ns
		V _{CC} = 2.0 V		-	20	39	-	46	ns
		V _{CC} = 2.7 V		-	15	29	-	34	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	10	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	11	23	-	27	ns
t _{en}	enable time	OEn to Yn; see Figure 6	[2]						
		V _{CC} = 1.2 V		-	100	-	-	-	ns
		V _{CC} = 2.0 V		-	34	65	-	77	ns
		$V_{CC} = 2.7 \text{ V}$		-	25	48	-	56	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	19	38	-	45	ns
t _{dis}	disable time	OEn to Yn; see Figure 6	[2]						
		V _{CC} = 1.2 V		-	100	-	-	-	ns
		V _{CC} = 2.0 V		-	36	66	-	78	ns
		V _{CC} = 2.7 V		-	27	48	-	58	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	21	39	-	47	ns

Octal buffer/line driver; 3-state

Table 7. **Dynamic characteristics** ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 7.

Symbol	Parameter	Conditions	-40	°C to +85	S °C	–40 °C 1	Unit		
				Min	Typ[1]	Max	Min	Max	
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	37	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} . ten is the same as tPZL and tPZH. t_{dis} is the same as t_{PLZ} and t_{PHZ}.
- [3] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$).
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz, f_o = output frequency in MHz

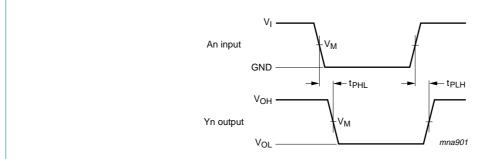
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms



Measurement points are given in Table 8.

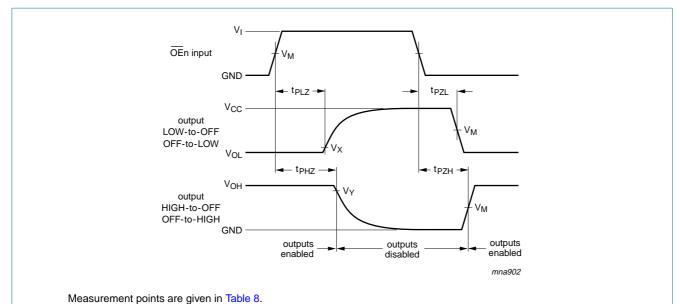
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Propagation delay input (An) to output (Yn) Fig 5.

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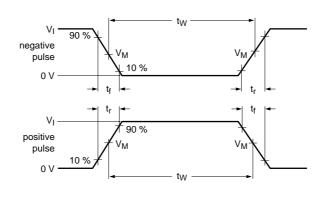
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

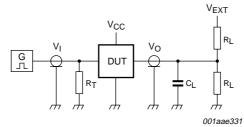
Fig 6. enable and disable times

Table 8. Measurement points

Supply voltage	Input	Output							
V _{CC}	V _M	V _M	V _X	V _Y					
< 2.7 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.1V_{CC}$	$V_{OH} - 0.1V_{CC}$					
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V					

Octal buffer/line driver; 3-state





Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Test circuit for measuring switching times Fig 7.

Table 9. Test data

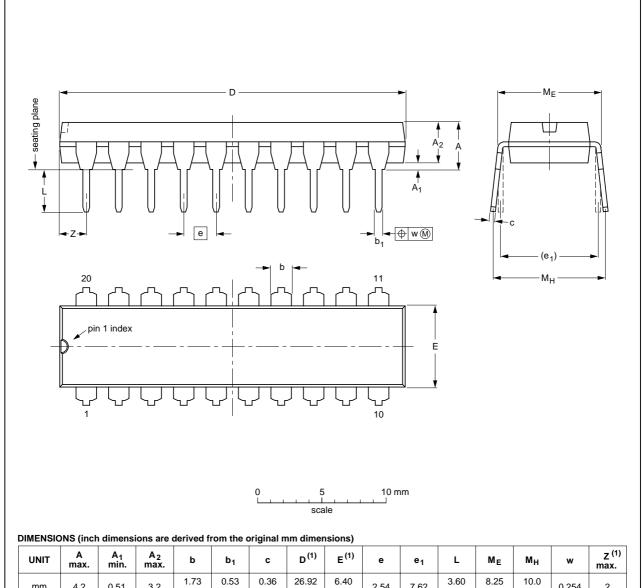
Supply voltage	Input		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
< 2.7 V	V_{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}	
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF, 50 pF	1 kΩ	open	GND	2V _{CC}	

Product data sheet

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

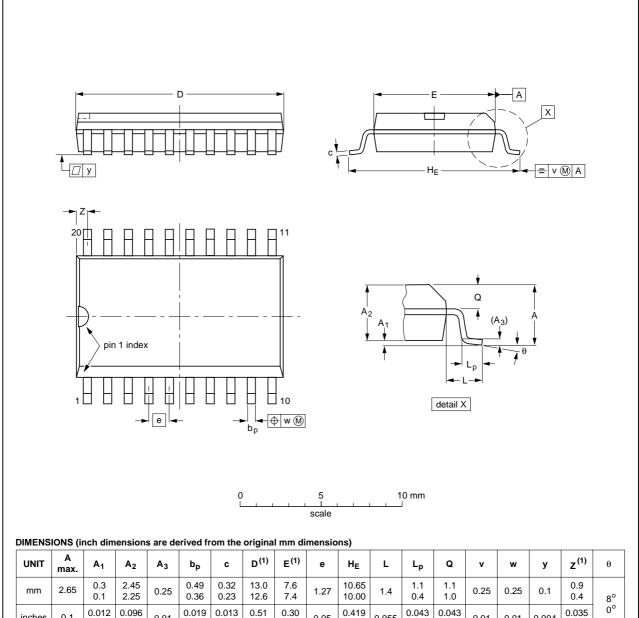
LINE		REFER	ENCES		EUROPEAN	ISSUE DATE
SION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
146-1		MS-001	SC-603			99-12-27 03-02-13
٤	SION	SION IEC	SION IEC JEDEC	SION IEC JEDEC JEITA	SION IEC JEDEC JEITA	SION IEC JEDEC JEITA PROJECTION

Fig 8. Package outline SOT146-1 (DIP20)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014		0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

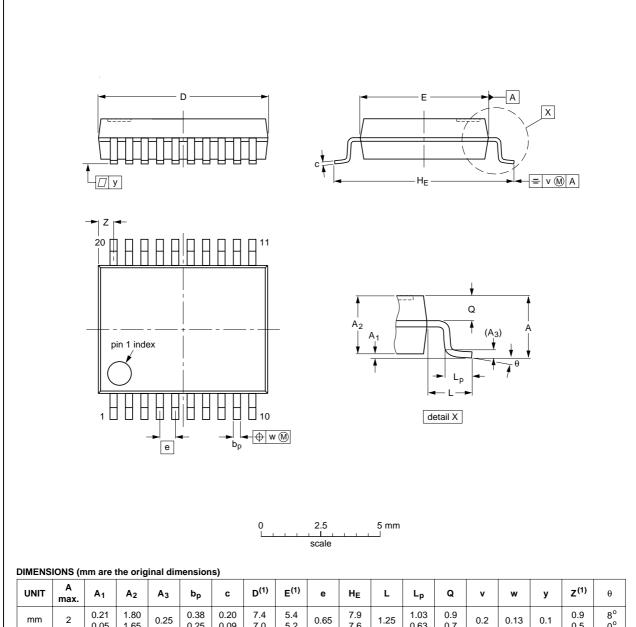
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013			99-12-27 03-02-19
				1	03-02-1

Fig 9. Package outline SOT163-1 (SO20)

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	Max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT339-1		MO-150				99-12-27 03-02-19

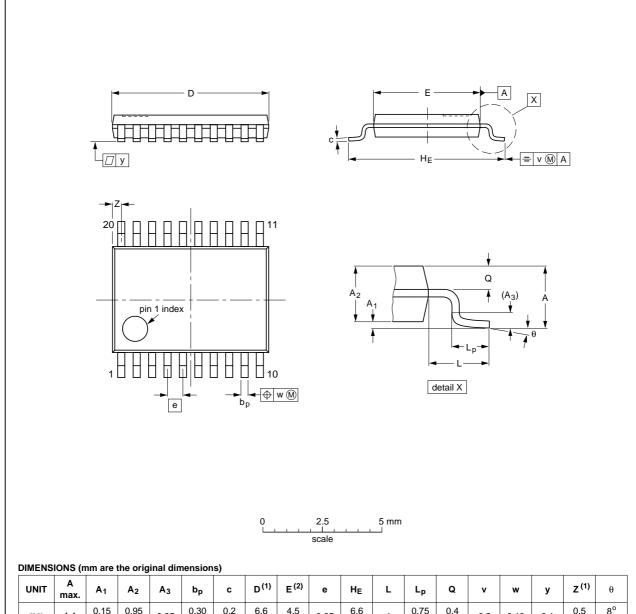
Fig 10. Package outline SOT339-1 (SSOP20)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

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UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

Product data sheet

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT360-1		MO-153			99-12-27 03-02-19

Fig 11. Package outline SOT360-1 (TSSOP20)

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Octal buffer/line driver; 3-state

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV541_3	20090414	Product data sheet	-	74LV541_2
Modifications:	 The format of th of NXP Semicor 		lesigned to comply with	the new identity guidelines
	 Legal texts have 	e been adapted to the new	company name when a	ppropriate.
74LV541_2	19980610	Product specification	-	74LV541_1
74LV541_1	19970304	Product specification	-	-

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Octal buffer/line driver; 3-state

15. Legal information

15.1 **Data sheet status**

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions'
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